



# TPS6256x 2.25MHz、600mA降圧型コンバータ、TSOTおよび2×2×0.8mm QFNパッケージ

## 1 特長

- 出力電流: 最大600mA
- 入力電圧範囲: 2.5V~5.5V
- PWMモード時の出力電圧精度±2.5%
- 静止電流: 15μA(標準値)
- 100%デューティ・サイクル動作により低いドロップアウト電圧を実現
- ソフト・スタート
- 小型のSOTおよび2mm×2mm×0.8mmのSONパッケージで供給
- 改良された機能セットについては、TPS62290デバイス(SLVS764)を参照してください。

## 2 アプリケーション

- PDA、Pocket PC、ポータブル・メディア・プレーヤー
- 低電力DSP電源
- ポイント・オブ・ロード(POL)アプリケーション

## 3 概要

TPS62560デバイスは、高効率の同期整流降圧型コンバータであり、電池式のポータブル・アプリケーションに最適です。単一のLiイオン電池や他のよく使われる単3および単4電池などから、最大600mAの電流を供給します。

入力電圧範囲が2.5~5.5Vのこのデバイスは、広範囲にわたる携帯用機器またはPOLアプリケーションへの電源供給を目的としています。

TPS62560ファミリーは、2.25MHzの固定スイッチング周波数で動作し、軽負荷電流時にはパワーセーブ・モードに自動的に切り替わり、広い負荷電流範囲にわたって高効率を維持します。

パワーセーブ・モードは、低出力電圧リップルに最適化されています。さらに低ノイズが要求されるアプリケーションの場合、本デバイスはMODEピンをHighにすることで、強制的に固定周波数PWMモードにすることができます。シャットダウン・モードでは、消費電流が1μA未満に低減します。TPS62560では、小型のインダクタとコンデンサを使用して、ソリューション・サイズを小さくすることができます。

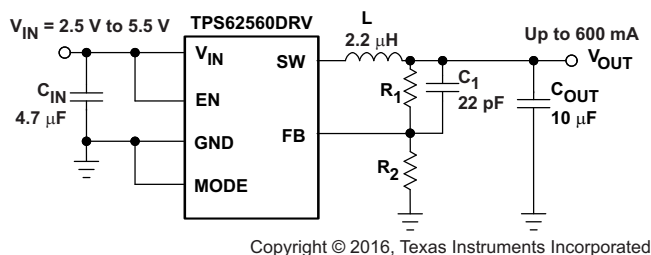
TPS62560とTPS62562は、6ピンの2mm×2mm SONパッケージ、TPS62561は5ピンのSOTパッケージで供給されます。

### 製品情報<sup>(1)</sup>

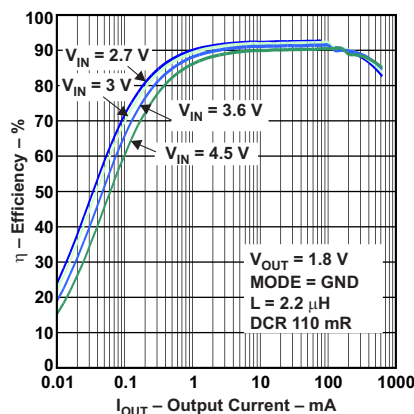
| 型番                | パッケージ   | 本体サイズ(公称)     |
|-------------------|---------|---------------|
| TPS62560、TPS62562 | SON (6) | 2.00mm×2.00mm |
| TPS62561          | SOT (5) | 2.90mm×1.60mm |

(1) 提供されているすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。

### 代表的なアプリケーションの回路図



### 効率と出力電流との関係



## 目次

|          |                                              |          |           |                                             |           |
|----------|----------------------------------------------|----------|-----------|---------------------------------------------|-----------|
| <b>1</b> | <b>特長</b> .....                              | <b>1</b> | <b>9</b>  | <b>Application and Implementation</b> ..... | <b>11</b> |
| <b>2</b> | <b>アプリケーション</b> .....                        | <b>1</b> | 9.1       | Application Information .....               | 11        |
| <b>3</b> | <b>概要</b> .....                              | <b>1</b> | 9.2       | Typical Application .....                   | 11        |
| <b>4</b> | <b>改訂履歴</b> .....                            | <b>2</b> | 9.3       | System Examples .....                       | 18        |
| <b>5</b> | <b>Device Comparison Table</b> .....         | <b>4</b> | <b>10</b> | <b>Power Supply Recommendations</b> .....   | <b>18</b> |
| <b>6</b> | <b>Pin Configuration and Functions</b> ..... | <b>4</b> | <b>11</b> | <b>Layout</b> .....                         | <b>19</b> |
| <b>7</b> | <b>Specifications</b> .....                  | <b>5</b> | 11.1      | Layout Guidelines .....                     | 19        |
| 7.1      | Absolute Maximum Ratings .....               | 5        | 11.2      | Layout Examples .....                       | 19        |
| 7.2      | ESD Ratings .....                            | 5        | <b>12</b> | <b>デバイスおよびドキュメントのサポート</b> .....             | <b>21</b> |
| 7.3      | Recommended Operating Conditions .....       | 5        | 12.1      | デバイス・サポート .....                             | 21        |
| 7.4      | Thermal Information .....                    | 5        | 12.2      | 関連リンク .....                                 | 21        |
| 7.5      | Electrical Characteristics .....             | 6        | 12.3      | ドキュメントの更新通知を受け取る方法 .....                    | 21        |
| 7.6      | Typical Characteristics .....                | 7        | 12.4      | コミュニティ・リソース .....                           | 21        |
| <b>8</b> | <b>Detailed Description</b> .....            | <b>8</b> | 12.5      | 商標 .....                                    | 21        |
| 8.1      | Overview .....                               | 8        | 12.6      | 静電気放電に関する注意事項 .....                         | 21        |
| 8.2      | Functional Block Diagram .....               | 8        | 12.7      | Glossary .....                              | 21        |
| 8.3      | Feature Description .....                    | 9        | <b>13</b> | <b>メカニカル、パッケージ、および注文情報</b> .....            | <b>21</b> |
| 8.4      | Device Functional Modes .....                | 10       |           |                                             |           |

## 4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

### Revision C (December 2009) から Revision D に変更

Page

|                                                                                                                                                             |           |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------|
| • 「ESD 定格」の表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加。 ..... | <b>1</b>  |
| • 注文情報の表を削除 .....                                                                                                                                           | <b>1</b>  |
| • テキスト文字列を「最大1000mAの出力電流」から「最大600mAの出力電流」に(「概要」) 変更 .....                                                                                                   | <b>1</b>  |
| • Corrected typographical errors in Figure 32; from "V <sub>IN</sub> = 2 V to 6 V" to "V <sub>IN</sub> = 2.5 V to 5.5 V" .....                              | <b>18</b> |

### Revision B (March 2009) から Revision C に変更

Page

|                                       |          |
|---------------------------------------|----------|
| • 高効率降圧型コンバータ 削除 .....                | <b>1</b> |
| • 「特長」の箇条書きの「広範な」削除 .....             | <b>1</b> |
| • 「特長」の「拡張電圧レンジ付きLiイオン電池の」削除 .....    | <b>1</b> |
| • 「特長」の「調整可能および固定の出力電圧オプション」削除 .....  | <b>1</b> |
| • 「特長」の「2.25MHz固定周波数動作」削除 .....       | <b>1</b> |
| • 「特長」の「軽負荷電流時のパワーセーブ・モード」削除 .....    | <b>1</b> |
| • 「特長」の「軽負荷電流時の電圧ポジショニング」削除 .....     | <b>1</b> |
| • 「特長」の「1mm未満のソリューション高が可能に」削除 .....   | <b>1</b> |
| • デバイスの機能およびTPS62260との相違点の詳細 変更 ..... | <b>1</b> |

### Revision A (July 2008) から Revision B に変更

Page

|                             |          |
|-----------------------------|----------|
| • TPS62562デバイスの番号を 追加 ..... | <b>1</b> |
|-----------------------------|----------|

**2008年1月発行のものから更新**

**Page**

- 
- 全レベルで変更。リビジョンAは本データシート全体の書き換えによって 変更 ..... [1](#)
-

## 5 Device Comparison Table

| Part Number | Package | Mode Pin        | Output Voltage <sup>(1)</sup> | Device Marking <sup>(2)</sup> |
|-------------|---------|-----------------|-------------------------------|-------------------------------|
| TPS62560    | SON (6) | yes             | Adjustable                    | CEY                           |
| TPS62561    | SOT (5) | forced PWM only | Adjustable                    | CVO                           |
| TPS62562    | SON (6) | yes             | 1.8 V fixed                   | NXT                           |

- (1) Contact TI for other fixed output voltage options  
(2) For the most current package and ordering information, see [メカニカル、パッケージ、および注文情報](#), or see the TI website at [www.ti.com](http://www.ti.com)

## 6 Pin Configuration and Functions



### Pin Functions

| NAME                | PIN       |              | I/O | DESCRIPTION                                                                                                                                                                                                                                       |
|---------------------|-----------|--------------|-----|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                     | No. QFN-6 | No. TSOT23-5 |     |                                                                                                                                                                                                                                                   |
| EN                  | 4         | 3            | I   | This is the enable pin of the device. Pulling this pin to low forces the device into shutdown mode. Pulling this pin to high enables the device. This pin must be terminated.                                                                     |
| FB                  | 3         | 4            | I   | Feedback pin for the internal regulation loop. Connect the external resistor divider to this pin. In the fixed-output-voltage option, connect this terminal directly to the output capacitor.                                                     |
| GND                 | 6         | 2            | —   | GND supply pin                                                                                                                                                                                                                                    |
| MODE                | 2         | N/A          | I   | This pin is only available as a QFN package option. MODE pin = high forces the device to operate in the fixed-frequency PWM mode. MODE pin = low enables the power-save mode with automatic transition from PFM mode to fixed-frequency PWM mode. |
| SW                  | 1         | 5            | O   | This is the switch pin and is connected to the internal MOSFET switches. Connect the external inductor between this pin and the output capacitor.                                                                                                 |
| $V_{IN}$            | 5         | 1            | —   | $V_{IN}$ power-supply pin                                                                                                                                                                                                                         |
| Exposed Thermal Pad | —         | N/A          | —   | Must be soldered to achieve appropriate power dissipation. Should be connected to GND.                                                                                                                                                            |

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                                                       | MIN                | MAX                    | UNIT |
|-------------------------------------------------------|--------------------|------------------------|------|
| Input voltage range <sup>(2)</sup>                    | −0.3               | 7                      | V    |
| Voltage range at EN, MODE                             | −0.3               | $V_{IN} + 0.3, \leq 7$ |      |
| Voltage on SW                                         | −0.3               | 7                      |      |
| Peak output current                                   | Internally limited |                        | A    |
| T <sub>J</sub> Maximum operating junction temperature | −40                | 125                    | °C   |
| T <sub>stg</sub> Storage temperature                  | −65                | 150                    | °C   |

- Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- All voltage values are with respect to the network ground terminal.

### 7.2 ESD Ratings

|                                                           |                                                                                | VALUE | UNIT |
|-----------------------------------------------------------|--------------------------------------------------------------------------------|-------|------|
| V <sub>(ESD)</sub> Electrostatic discharge <sup>(1)</sup> | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(2)</sup>              | ±2000 | V    |
|                                                           | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(3)</sup> | ±1000 |      |
|                                                           | Machine model                                                                  | ±200  |      |

- The human-body model is a 100-pF capacitor discharged through a 1.5-kΩ resistor into each terminal. The machine model is a 200-pF capacitor discharged directly into each terminal.
- JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.
- JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.

### 7.3 Recommended Operating Conditions

|                                                              | MIN  | MAX             | UNIT |
|--------------------------------------------------------------|------|-----------------|------|
| V <sub>IN</sub> Supply voltage                               | 2.5  | 5.5             | V    |
| V <sub>OUT</sub> Output voltage range for adjustable voltage | 0.85 | V <sub>IN</sub> | V    |
| T <sub>A</sub> Operating ambient temperature                 | −40  | 85              | °C   |
| T <sub>J</sub> Operating junction temperature                | −40  | 125             | °C   |

### 7.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | TPS62560,<br>TPS62562 | TPS62561  | UNIT |
|-------------------------------|----------------------------------------------|-----------------------|-----------|------|
|                               |                                              | DRV (SON)             | DDC (SOT) |      |
|                               |                                              | 6 PINS                | 5 PINS    |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 67.8                  | 226.9     | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 88.5                  | 40.7      | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 37.2                  | 48.8      | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 2.0                   | 0.5       | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 37.6                  | 48.1      | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | 7.9                   | n/a       | °C/W |

- For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 7.5 Electrical Characteristics

Over full operating ambient temperature range, typical values are at  $T_A = 25^\circ\text{C}$ . Unless otherwise noted, specifications apply for condition  $V_{IN} = EN = 3.6\text{ V}$ . External components  $C_{IN} = 4.7\text{ }\mu\text{F}$  0603,  $C_{OUT} = 10\text{ }\mu\text{F}$  0603,  $L = 2.2\text{ }\mu\text{H}$

| PARAMETER             |                                                 | TEST CONDITIONS                                                                                                                                                                      | MIN   | TYP  | MAX             | UNIT |
|-----------------------|-------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|------|-----------------|------|
| SUPPLY                |                                                 |                                                                                                                                                                                      |       |      |                 |      |
| V <sub>IN</sub>       | Input voltage range                             |                                                                                                                                                                                      | 2.5   |      | 5.5             | V    |
| I <sub>OUT</sub>      | Output current                                  | V <sub>IN</sub> 2.5 V to 5.5 V                                                                                                                                                       |       |      | 600             | mA   |
| I <sub>Q</sub>        | Operating quiescent current                     | I <sub>OUT</sub> = 0 mA, PFM mode enabled (MODE = GND), device not switching                                                                                                         |       | 15   |                 | μA   |
|                       |                                                 | I <sub>OUT</sub> = 0 mA, PFM mode enabled (MODE = GND), device switching, V <sub>OUT</sub> = 1.8 V, See (1)                                                                          |       | 18.5 |                 |      |
|                       |                                                 | I <sub>OUT</sub> = 0 mA, switching with no load (MODE = V <sub>IN</sub> ), PWM operation, V <sub>OUT</sub> = 1.8 V, V <sub>IN</sub> = 3 V                                            |       | 3.8  |                 | mA   |
| I <sub>SD</sub>       | Shutdown current                                | EN = GND                                                                                                                                                                             |       | 0.5  |                 | μA   |
| UVLO                  | Undervoltage lockout threshold                  | Falling                                                                                                                                                                              |       | 1.85 |                 | V    |
|                       |                                                 | Rising                                                                                                                                                                               |       | 1.95 |                 |      |
| ENABLE, MODE          |                                                 |                                                                                                                                                                                      |       |      |                 |      |
| V <sub>IH</sub>       | High-level input voltage, EN, MODE              | 2 V ≤ V <sub>IN</sub> ≤ 5.5 V                                                                                                                                                        | 1     |      | V <sub>IN</sub> | V    |
| V <sub>IL</sub>       | Low-level input voltage, EN, MODE               | 2 V ≤ V <sub>IN</sub> ≤ 5.5 V                                                                                                                                                        | 0     |      | 0.4             | V    |
| I <sub>IN</sub>       | Input bias current, EN, MODE                    | EN, MODE = GND or V <sub>IN</sub>                                                                                                                                                    |       | 0.01 | 1               | μA   |
| POWER SWITCH          |                                                 |                                                                                                                                                                                      |       |      |                 |      |
| R <sub>DS(on)</sub>   | High side MOSFET on-resistance                  | V <sub>IN</sub> = V <sub>GS</sub> = 3.6 V, T <sub>A</sub> = 25°C                                                                                                                     |       | 252  | 492             | mΩ   |
|                       | Low side MOSFET on-resistance                   |                                                                                                                                                                                      |       | 194  | 391             |      |
| I <sub>LIMF</sub>     | Forward current limit, high and low side MOSFET | V <sub>IN</sub> = V <sub>GS</sub> = 3.6 V                                                                                                                                            | 0.8   | 1    | 1.2             | A    |
| T <sub>SD</sub>       | Thermal shutdown                                | Increasing junction temperature                                                                                                                                                      |       | 140  |                 | °C   |
|                       | Thermal-shutdown hysteresis                     | Decreasing junction temperature                                                                                                                                                      |       | 20   |                 |      |
| OSCILLATOR            |                                                 |                                                                                                                                                                                      |       |      |                 |      |
| f <sub>SW</sub>       | Oscillator frequency                            | 2 V ≤ V <sub>IN</sub> ≤ 5.5 V                                                                                                                                                        |       | 2.25 |                 | MHz  |
| OUTPUT                |                                                 |                                                                                                                                                                                      |       |      |                 |      |
| V <sub>OUT</sub>      | Adjustable-output voltage range                 |                                                                                                                                                                                      | 0.85  |      | V <sub>IN</sub> | V    |
| V <sub>OUT</sub>      | TPS62562 fixed output voltage                   | V <sub>IN</sub> ≥ 1.8 V                                                                                                                                                              |       | 1.8  |                 | V    |
| V <sub>ref</sub>      | Reference voltage                               |                                                                                                                                                                                      |       | 600  |                 | mV   |
| V <sub>FB</sub>       | Feedback voltage, PWM mode                      | MODE = V <sub>IN</sub> , PWM operation, for fixed-output-voltage versions V <sub>FB</sub> = V <sub>OUT</sub> , 2.5 V ≤ V <sub>IN</sub> ≤ 5.5 V, 0 mA ≤ I <sub>OUT</sub> ≤ 600 mA (2) | −2.5% | 0%   | 2.5%            |      |
|                       | Feedback voltage, PFM mode                      | MODE = GND, device in PFM mode, voltage positioning active (1)                                                                                                                       |       | 1%   |                 |      |
|                       | Load regulation                                 | PWM mode                                                                                                                                                                             |       | −1   |                 |      |
| t <sub>Start Up</sub> | Start-up time                                   | Time from active EN to reach 95% of V <sub>OUT</sub> nominal                                                                                                                         |       | 500  |                 | μs   |
| t <sub>Ramp</sub>     | V <sub>OUT</sub> ramp-up time                   | Time to ramp from 5% to 95% of V <sub>OUT</sub>                                                                                                                                      |       | 250  |                 | μs   |
| I <sub>lkg</sub>      | Leakage current into SW terminal                | V <sub>IN</sub> = 3.6 V, V <sub>IN</sub> = V <sub>OUT</sub> = V <sub>SW</sub> , EN = GND (3)                                                                                         |       | 0.5  | 1               | μA   |

(1) In PFM mode, the internal reference voltage is set to typ.  $1.01 \times V_{ref}$ . See the section.

(2) For  $V_{IN} = V_{OUT} + 0.6\text{ V}$

(3) In fixed-output-voltage versions, the internal resistor divider network is disconnected from the FB terminal.

## 7.6 Typical Characteristics

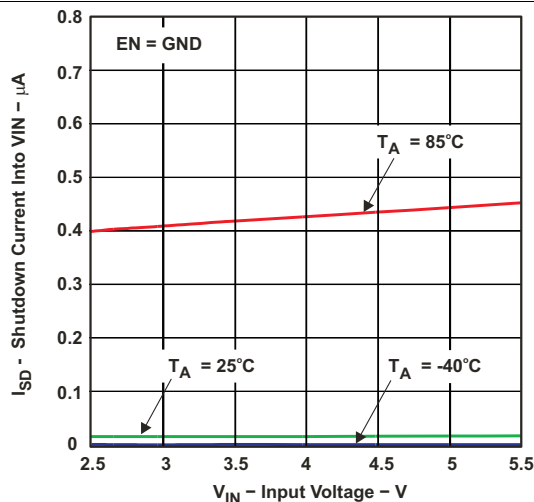


Figure 1. Shutdown Current into VIN vs Input Voltage

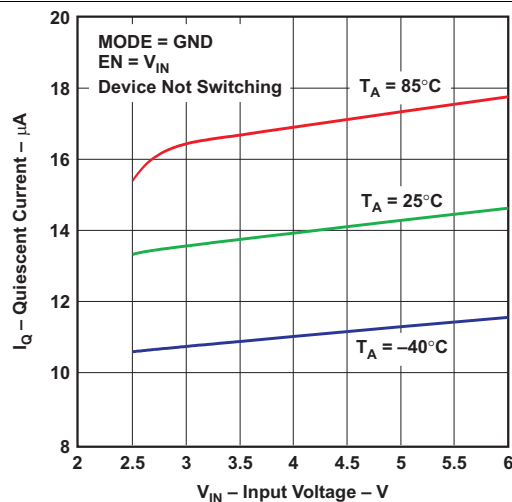


Figure 2. Quiescent Current vs Input Voltage

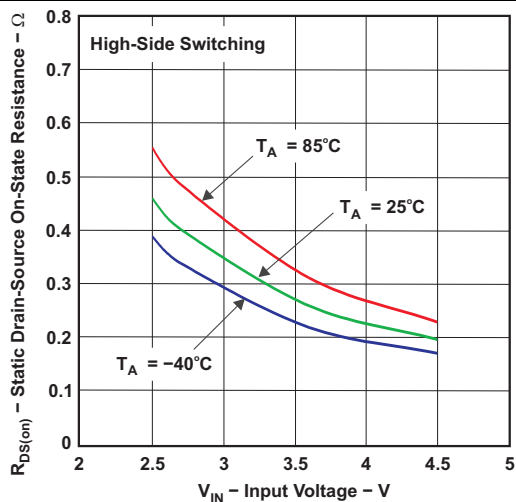


Figure 3. Static Drain-Source ON-State Resistance

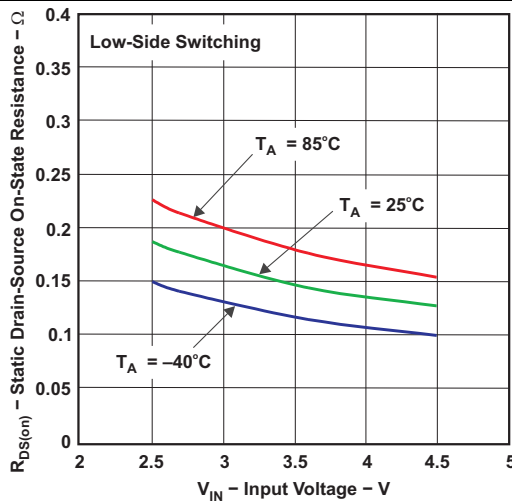


Figure 4. Static Drain-Source ON-State Resistance vs Input Voltage

## 8 Detailed Description

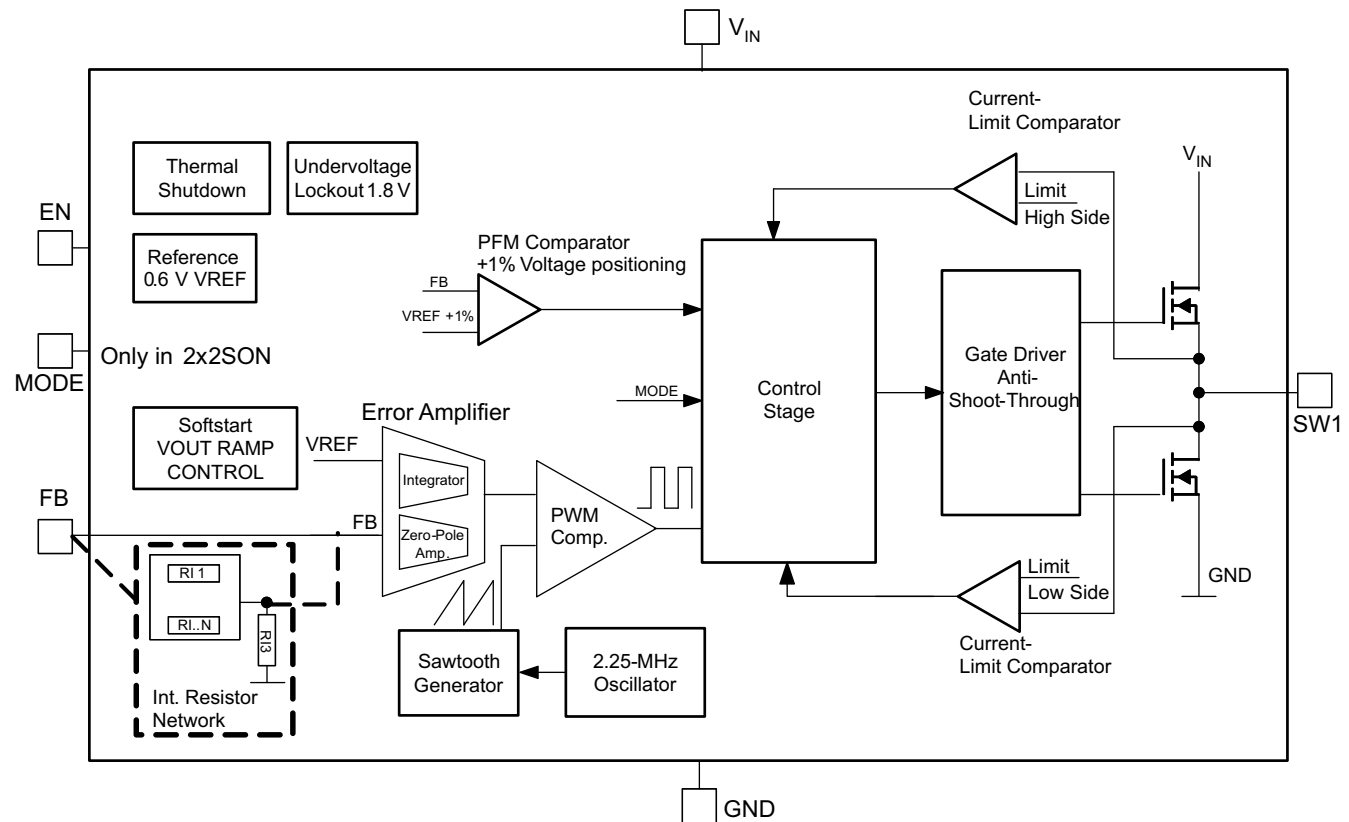
### 8.1 Overview

The TPS62560/62 step-down converters operate with typically 2.25-MHz fixed-frequency pulse-width modulation (PWM) at moderate to heavy load currents. At light load currents, the converter can automatically enter power-save mode, and then operates in PFM mode. However, the TPS62561 operates with fixed-frequency PWM only, also at light load conditions.

During PWM operation, the converter uses a unique fast-response voltage-mode control scheme with input-voltage feed-forward to achieve good line and load regulation, allowing the use of small ceramic input and output capacitors. At the beginning of each clock cycle initiated by the clock signal, the high-side MOSFET switch is turned on. The current flows from the input capacitor via the high-side MOSFET switch through the inductor to the output capacitor and load. During this phase, the current ramps up until the PWM comparator trips and the control logic turns off the switch. The current-limit comparator also turns off the switch in case the current limit of the high-side MOSFET switch is exceeded. After a dead time, which prevents shoot-through current, the low-side MOSFET rectifier is turned on and the inductor current ramps down. The current flows from the inductor to the output capacitor and to the load. It returns back to the inductor through the low-side MOSFET rectifier.

The next cycle is initiated by the clock signal again turning off the low-side MOSFET rectifier and turning on the on the high-side MOSFET switch.

### 8.2 Functional Block Diagram



Copyright © 2016, Texas Instruments Incorporated

## 8.3 Feature Description

### 8.3.1 Dynamic Voltage Positioning

This feature reduces the voltage under/overshoots at load steps from light to heavy load and vice versa. It is active in power-save mode and regulates the output voltage 1% higher than the nominal value. This provides more headroom for both the voltage drop at a load step, and the voltage increase at a load throw-off.

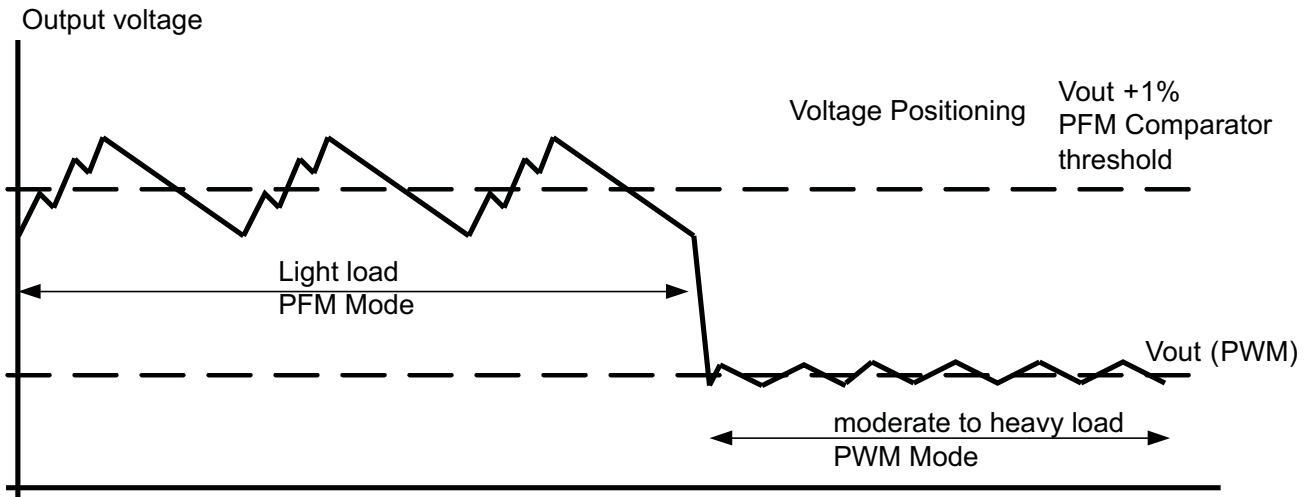


Figure 5. Power Save Mode Operation With Automatic Mode Transition

### 8.3.2 Undervoltage Lockout

The undervoltage lockout circuit prevents the device from malfunctioning at low input voltages and from excessive discharge of the battery and disables the output stage of the converter. The undervoltage lockout threshold is typically 1.85 V with falling  $V_{IN}$ .

### 8.3.3 Mode Selection

The MODE terminal allows mode selection between forced-PWM mode and power-save mode.

Connecting this terminal to GND enables the power-save mode with automatic transition between PWM and PFM modes. Pulling the MODE terminal high forces the converter to operate in fixed-frequency PWM mode even at light load currents. This allows simple filtering of the switching frequency for noise-sensitive applications. In this mode, the efficiency is lower compared to the power-save mode during light loads.

The state of the MODE terminal can be changed during operation to allow efficient power management by adjusting the operation mode of the converter to the specific system requirements.

### 8.3.4 Enable

The device is enabled by setting the EN terminal to high. During the start-up time  $t_{Start Up}$ , the internal circuits are settled and the soft-start circuit is activated. The EN input can be used to control power sequencing in a system with various dc/dc converters. The EN terminal can be connected to the output of another converter, to drive the EN terminal high to achieve a sequencing of the given supply rails. With EN = GND, the device enters shutdown mode, in which all internal circuits are disabled. In fixed-output-voltage versions, the internal resistor divider network is then disconnected from the FB terminal.

### 8.3.5 Thermal Shutdown

As soon as the junction temperature,  $T_J$ , exceeds 140°C (typical), the device goes into thermal shutdown. In this mode, the high-side and low-side MOSFETs are turned off. The device continues its operation when the junction temperature falls below the thermal shutdown hysteresis.

## 8.4 Device Functional Modes

### 8.4.1 Soft-Start

The TPS62560 has an internal soft-start circuit that controls the ramp-up of the output voltage. The output voltage ramps up from 5% to 95% of its nominal value typically within 250  $\mu$ s. This limits the inrush current into the converter during ramp-up and prevents possible input voltage drops when a battery or high-impedance power source is used. The soft-start circuit is enabled within the start-up time  $t_{Start Up}$ .

### 8.4.2 Power-Save Mode

The power-save mode is enabled with the MODE terminal set to the low level. If the load current decreases, the converter enters the power-save mode of operation automatically. During power-save mode, the converter skips switching and operates with reduced frequency in PFM mode with a minimum quiescent current to maintain high efficiency. The converter positions the output voltage typically 1% above the nominal output voltage. This voltage positioning feature minimizes voltage drops caused by a sudden load step.

The transition from PWM mode to PFM mode occurs once the inductor current in the low-side MOSFET switch becomes zero, which indicates discontinuous conduction mode.

During the power-save mode, the output voltage is monitored with a PFM comparator. As the output voltage falls below the PFM comparator threshold of  $V_{OUT}$  nominal + 1%, the device starts a PFM current pulse. The high-side MOSFET switch turns on, and the inductor current ramps up. After the on-time expires, the switch is turned off and the low-side MOSFET switch is turned on until the inductor current becomes zero.

The converter effectively delivers a current to the output capacitor and the load. If the load is below the delivered current, the output voltage rises. If the output voltage is equal to or higher than the PFM comparator threshold, the device stops switching and enters a sleep mode with typical 15- $\mu$ A current consumption.

If the output voltage is still below the PFM comparator threshold, a sequence of further PFM current pulses is generated until the PFM comparator threshold is reached. The converter starts switching again once the output voltage drops below the PFM comparator threshold.

With a fast single-threshold comparator, the output-voltage ripple during PFM-mode operation can be kept small. The PFM pulse is time controlled, which allows modifying the charge transferred to the output capacitor by the value of the inductor. The resulting PFM output-voltage ripple and PFM frequency depend primarily on the size of the output capacitor and the inductor value. Increasing output capacitor values and inductor values minimizes the output ripple. The PFM frequency decreases with smaller inductor values and increases with larger values.

The PFM mode is left and PWM mode entered in case the output current can no longer be supported in PFM mode. The power-save mode can be disabled by setting the MODE terminal to high. The converter then operates in the fixed-frequency PWM mode.

#### 8.4.2.1 100% Duty-Cycle Low-Dropout Operation

The device starts to enter 100% duty-cycle mode once the input voltage comes close to the nominal output voltage. In order to maintain the output voltage, the high-side MOSFET switch is turned on 100% for one or more cycles.

With further decreasing  $V_{IN}$ , the high-side MOSFET switch is turned on completely. In this case, the converter offers a low input-to-output voltage difference. This is particularly useful in battery-powered applications to achieve longest operation time by taking full advantage of the whole battery-voltage range.

The minimum input voltage to maintain regulation depends on the load current and output voltage; and, can be calculated as:

$$V_{INmin} = V_{OUTmax} + I_{OUTmax} \times (R_{DS(on)}max + R_L)$$

where

- $I_{OUTmax}$  = maximum output current plus inductor ripple current
- $R_{DS(on)}max$  = maximum P-channel switch  $R_{DS(on)}$
- $R_L$  = dc resistance of the inductor
- $V_{OUTmax}$  = nominal output voltage plus maximum output voltage tolerance

(1)

## Device Functional Modes (continued)

### 8.4.2.2 Short-Circuit Protection

The high-side and low-side MOSFET switches are short-circuit protected with maximum switch current =  $I_{LIMF}$ . The current in the switches is monitored by current-limit comparators. Once the current in the high-side MOSFET switch exceeds the threshold of its current-limit comparator, it turns off and the low-side MOSFET switch is activated to ramp down the current in the inductor and high-side MOSFET switch. The high-side MOSFET switch can only turn on again after the current in the low-side MOSFET switch has decreased below the threshold of its current-limit comparator.

## 9 Application and Implementation

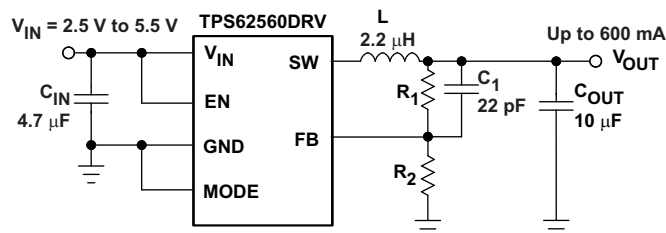
### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The TPS6256x devices are high-efficiency synchronous step-down DC–DC converter featuring power-save mode or 2.25-MHz fixed frequency operation.

### 9.2 Typical Application



Copyright © 2016, Texas Instruments Incorporated

**Figure 6. TPS62560DRV Adjustable**

#### 9.2.1 Design Requirements

The TPS6256x is a highly integrated DC/DC converter. The output voltage is set with an external voltage divider for the adjustable output voltage version. The output voltage is fixed to 1.8V for the TPS62562. For proper operation a input- and output capacitor and an inductor is required. Table 2 shows the components used for the application characteristic curves.

#### 9.2.2 Detailed Design Procedure

##### 9.2.2.1 Output Voltage Setting

For adjustable output voltage versions, the output voltage can be calculated by [Equation 2](#) with the internal reference voltage  $V_{REF} = 0.6\text{ V}$  typically.

$$V_{OUT} = V_{REF} \times \left( 1 + \frac{R_1}{R_2} \right) \quad (2)$$

To minimize the current through the feedback divider network,  $R_2$  should be 180 kΩ or 360 kΩ. The sum of  $R_1$  and  $R_2$  should not exceed ~1 MΩ, to keep the network robust against noise. An external feed-forward capacitor  $C_1$  is required for optimum load transient response. The value of  $C_1$  should be in the range between 22 pF and 33 pF.

In case of using the fixed output voltage version (TPS62562),  $V_{out}$  has to be connected to the feedback pin FB.

## Typical Application (continued)

Route the FB line away from noise sources, such as the inductor or the SW line.

### 9.2.2.2 Output Filter Design (inductor and Output Capacitor)

The TPS62560 is designed to operate with inductors in the range of 1.5  $\mu\text{H}$  to 4.7  $\mu\text{H}$  and with output capacitors in the range of 4.7  $\mu\text{F}$  to 22  $\mu\text{F}$ . The part is optimized for operation with a 2.2- $\mu\text{H}$  inductor and 10- $\mu\text{F}$  output capacitor.

Larger or smaller inductor values can be used to optimize the performance of the device for specific operation conditions. For stable operation, the L and C values of the output filter may not fall below 1  $\mu\text{H}$  effective inductance and 3.5  $\mu\text{F}$  effective capacitance.

#### 9.2.2.2.1 Inductor Selection

The inductor value has a direct effect on the ripple current. The selected inductor must be rated for its dc resistance and saturation current. The inductor ripple current ( $\Delta I_L$ ) decreases with higher inductance and increases with higher  $V_{\text{IN}}$  or  $V_{\text{OUT}}$ .

The inductor selection also impacts the output voltage ripple in PFM mode. Higher inductor values lead to lower output voltage ripple and higher PFM frequency; lower inductor values lead to a higher output voltage ripple but lower PFM frequency.

[Equation 3](#) calculates the maximum inductor current in PWM mode under static load conditions. The saturation current of the inductor should be rated higher than the maximum inductor current as calculated with [Equation 4](#). This is recommended because during heavy load transients the inductor current rises above the calculated value.

$$\Delta I_L = V_{\text{OUT}} \times \frac{1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}}{L \times f} \quad (3)$$

$$I_{L \text{ max}} = I_{\text{out max}} + \frac{\Delta I_L}{2}$$

where

- $f$  = Switching frequency (2.25 MHz, typical)
  - $L$  = Inductor value
  - $\Delta I_L$  = Peak-to-peak inductor ripple current
  - $I_{L \text{ max}}$  = Maximum inductor current
- (4)

A more conservative approach is to select the inductor current rating just for the switch current limit  $I_{\text{LIMF}}$  of the converter.

Accepting larger values of ripple current allows the use of lower inductance values, but results in higher output voltage ripple, greater core losses, and lower output current capability.

The total losses of the coil have a strong impact on the efficiency of the dc/dc conversion and consist of both the losses in the dc resistance ( $R_{\text{DC}}$ ) and the following frequency-dependent components:

- The losses in the core material (magnetic hysteresis loss, especially at high switching frequencies)
- Additional losses in the conductor from the skin effect (current displacement at high frequencies)
- Magnetic field losses of the neighboring windings (proximity effect)
- Radiation losses

**Table 1. List of Inductors**

| DIMENSIONS, mm    | INDUCTANCE, $\mu$ H | INDUCTOR TYPE    | SUPPLIER <sup>(1)</sup> |
|-------------------|---------------------|------------------|-------------------------|
| 2,5 × 2 × 1 max   | 2                   | MIPS2520D2R2     | FDK                     |
| 2,5 × 2 × 1,2 max | 2                   | MIPSA2520D2R2    | FDK                     |
| 2,5 × 2 × 1 max   | 2.2                 | KSLI-252010AG2R2 | Hitachi Metals          |
| 2,5 × 2 × 1,2 max | 2.2                 | LQM2HPN2R2MJ0L   | Murata                  |
| 3 × 3 × 1,5 max   | 2.2                 | LPS3015 2R2      | Coilcraft               |

(1) See [Third-Party Products Disclaimer](#)

#### 9.2.2.2.2 Output Capacitor Selection

The advanced fast-response voltage-mode control scheme of the TPS62560 allows the use of tiny ceramic capacitors. Ceramic capacitors with low ESR values have the lowest output voltage ripple and are recommended. The output capacitor requires either an X7R or X5R dielectric. Y5V and Z5U dielectric capacitors, aside from their wide variation in capacitance over temperature, become resistive at high frequencies.

At nominal load current, the device operates in PWM mode, and the RMS ripple current is calculated by [Equation 5](#):

$$I_{\text{RMS}C_{\text{OUT}}} = V_{\text{OUT}} \times \frac{1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}}{L \times f} \times \frac{1}{2\sqrt{3}} \quad (5)$$

At nominal load current, the device operates in PWM mode, and the overall output voltage ripple is the sum of the voltage spike caused by the output capacitor ESR plus the voltage ripple caused by charging and discharging the output capacitor shown in [Equation 6](#):

$$\Delta V_{\text{OUT}} = V_{\text{OUT}} \times \frac{1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}}{L \times f} \times \left( \frac{1}{8 \times C_{\text{OUT}} \times f} + \text{ESR} \right) \quad (6)$$

At light load currents, the converter operates in power-save mode, and the output voltage ripple is dependent on the output capacitor and inductor values. Larger output capacitor and inductor values minimize the voltage ripple in PFM mode and tighten dc output accuracy in PFM mode.

#### 9.2.2.2.3 Input Capacitor Selection

An input capacitor is required for best input voltage filtering and minimizing the interference with other circuits caused by high input voltage spikes. For most applications, a 4.7- $\mu$ F to 10- $\mu$ F ceramic capacitor is recommended. Because a ceramic capacitor loses up to 80% of its initial capacitance at 5 V, it is recommended that 10- $\mu$ F input capacitors be used for input voltages > 4.5 V. The input capacitor can be increased without any limit for better input voltage filtering. Take care when using only small ceramic input capacitors. When a ceramic capacitor is used at the input and the power is being supplied through long wires, such as from a wall adapter, a load step at the output or  $V_{\text{IN}}$  step on the input can induce ringing at the  $V_{\text{IN}}$  terminal. This ringing can couple to the output and be mistaken as loop instability or could even damage the part by exceeding the maximum ratings.

**Table 2. List of Capacitors<sup>(1)</sup>**

| CAPACITANCE | TYPE              | SIZE                    | SUPPLIER |
|-------------|-------------------|-------------------------|----------|
| 4.7 $\mu$ F | GRM188R60J475K    | 0603—1,6 × 0,8 × 0,8 mm | Murata   |
| 10 $\mu$ F  | GRM188R60J106M69D | 0603—1,6 × 0,8 × 0,8 mm | Murata   |

(1) See [Third-Party Products Disclaimer](#)

## 9.2.3 Application Curves

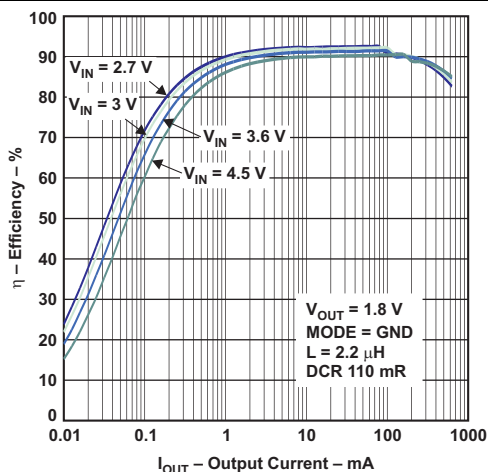


Figure 7. Efficiency vs Output Current

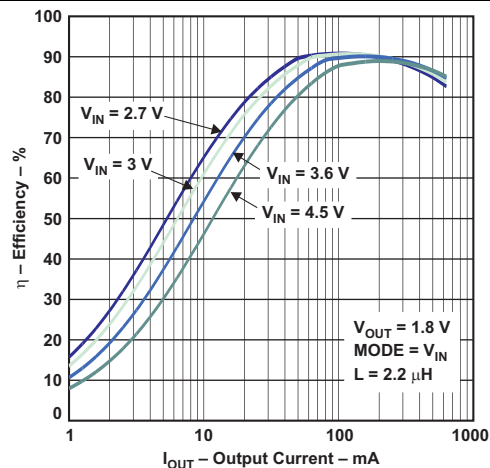


Figure 8. Efficiency vs Output Current

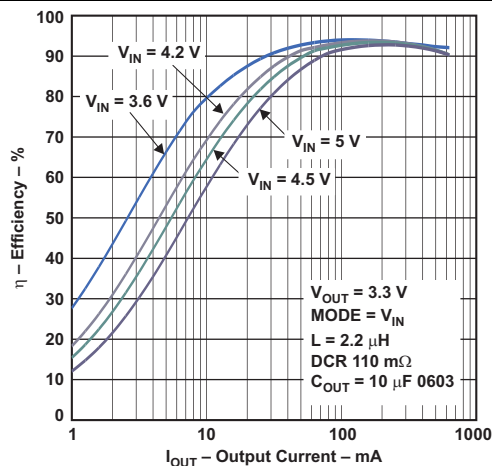


Figure 9. Efficiency vs Output Current

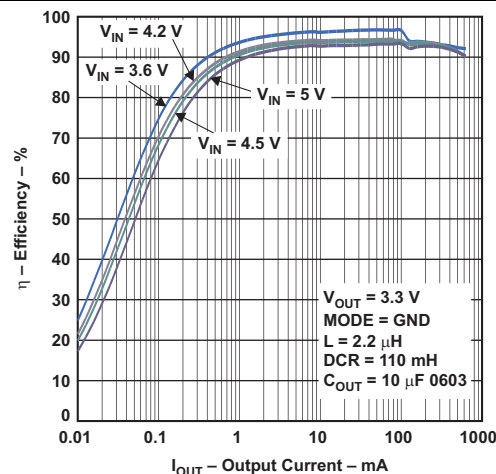


Figure 10. Efficiency vs Output Current

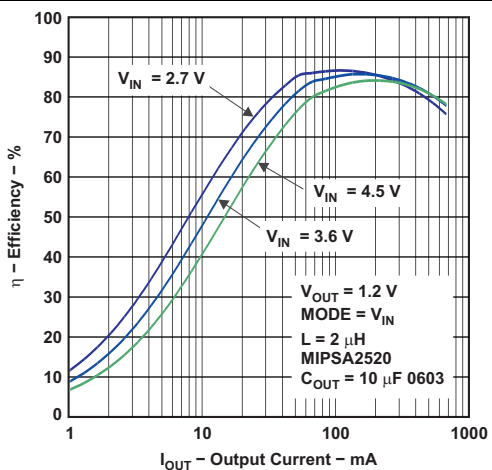


Figure 11. Efficiency vs Output Current

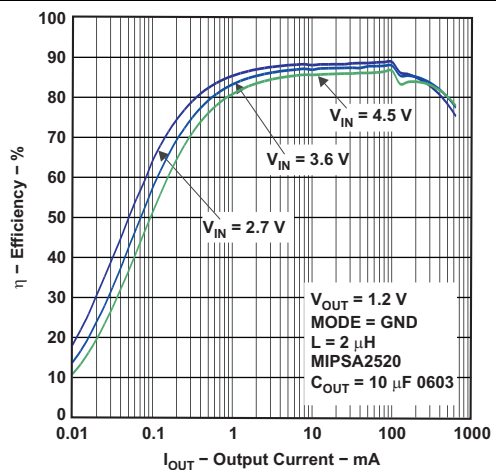


Figure 12. Efficiency vs Output Current

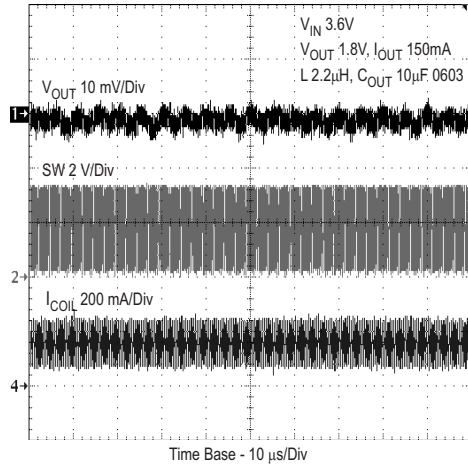


Figure 13. Typical Operation - PWM Mode

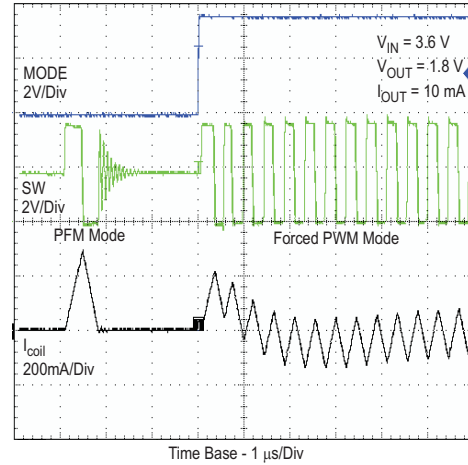


Figure 14. Mode Pin Transition from PFM to FORCED PWM Mode at Light Load

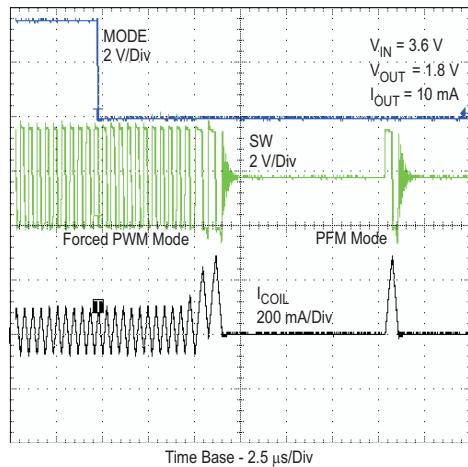


Figure 15. Mode Pin Transition from PWM to PFM MODE at Light Load

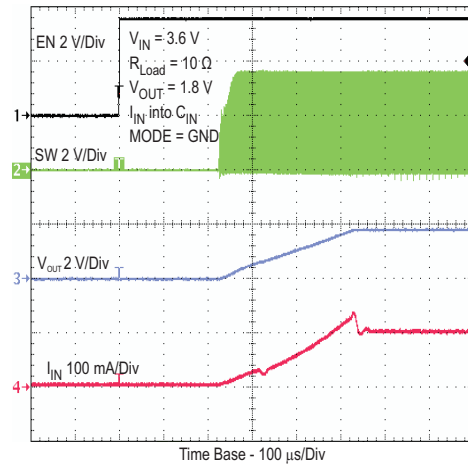


Figure 16. Start-UP Timing

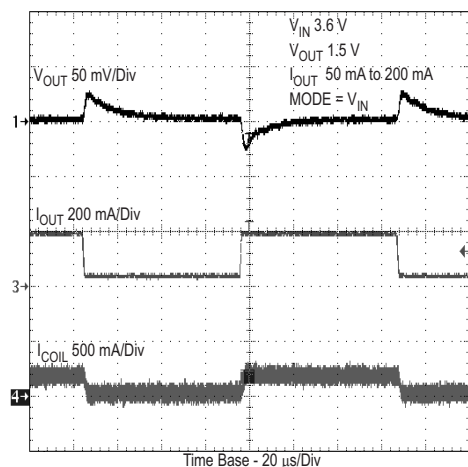


Figure 17. Forced PWM Load Transient

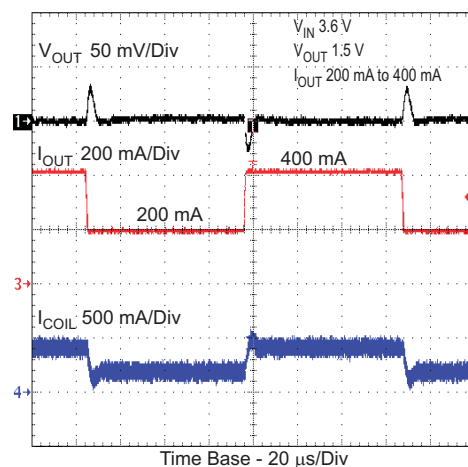


Figure 18. Forced PWM Load Transient

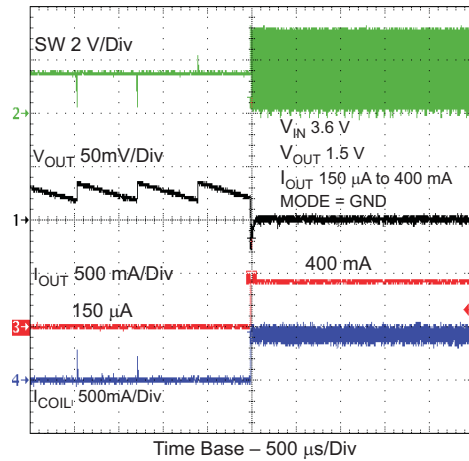


Figure 19. PFM Load Transient

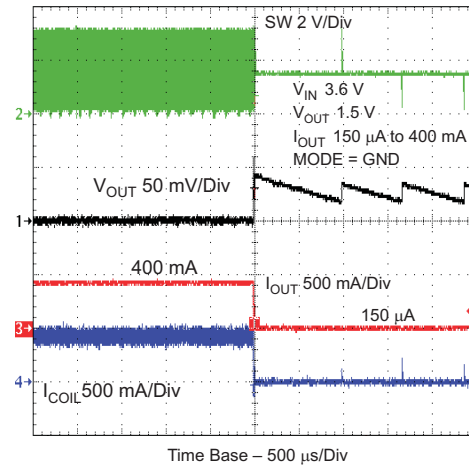


Figure 20. PFM Load Transient

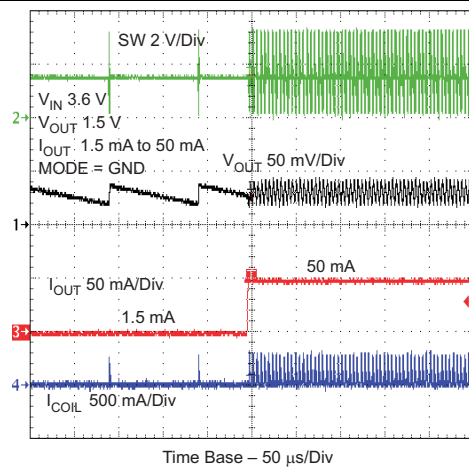


Figure 21. PFM Load Transient

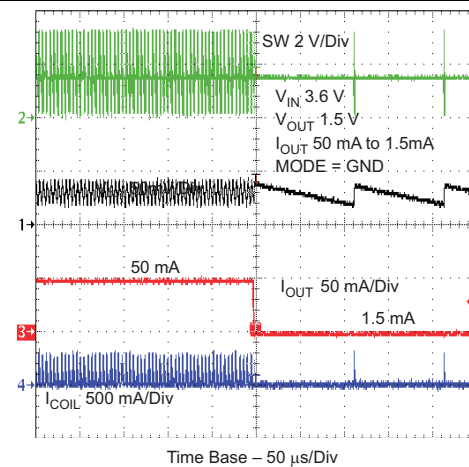


Figure 22. PFM Load Transient

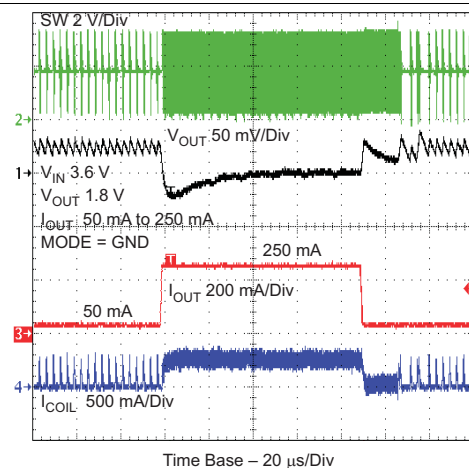


Figure 23. PFM Load Transient

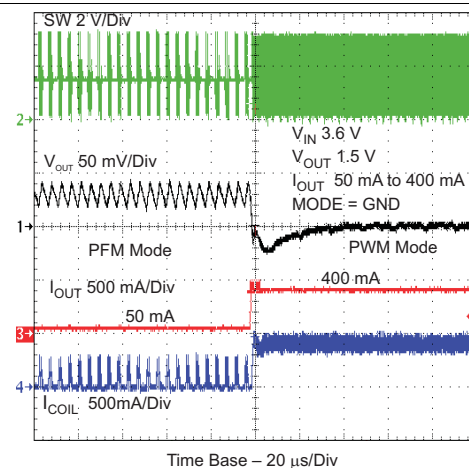
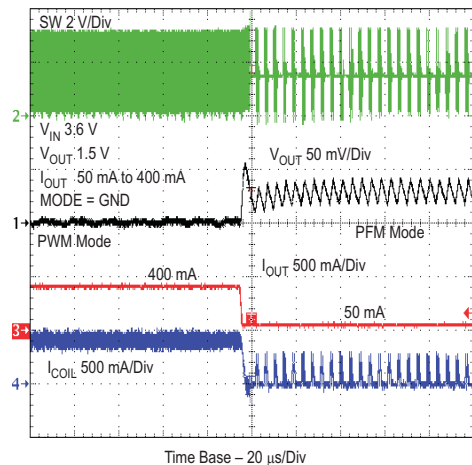
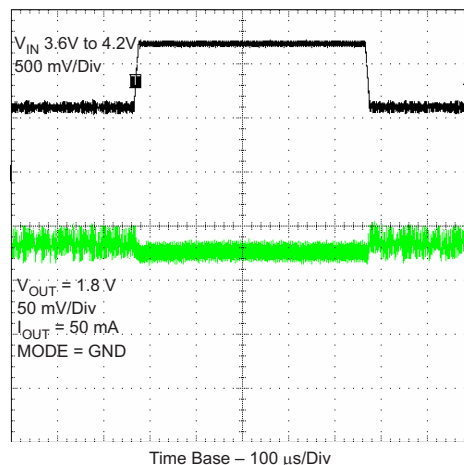


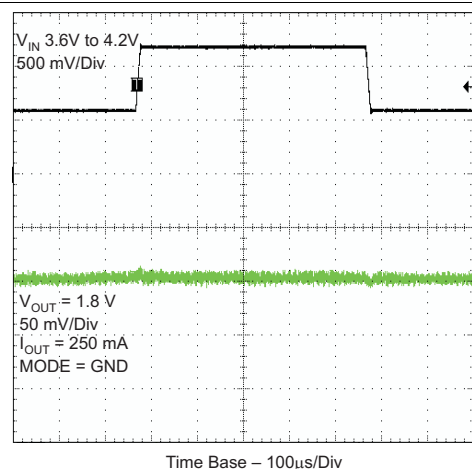
Figure 24. PFM Load Transient



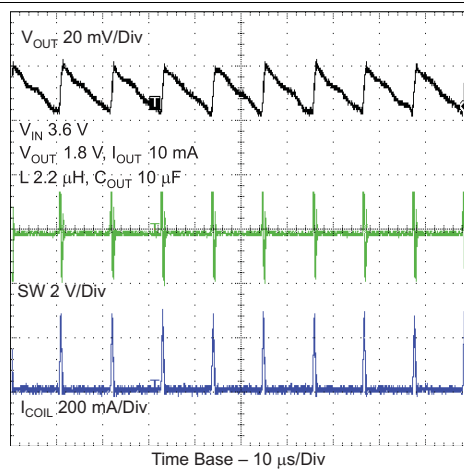
**Figure 25. PFM Load Transient**



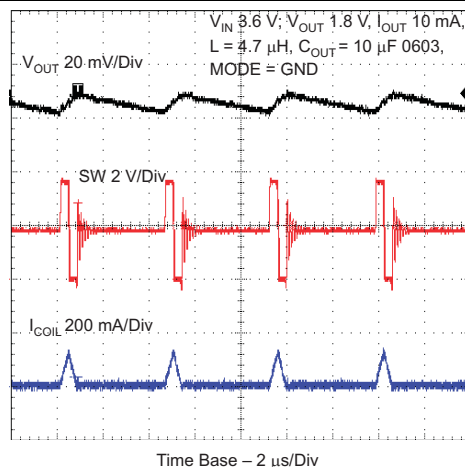
**Figure 26. PFM Line Transient**



**Figure 27. PWM Line Transient**

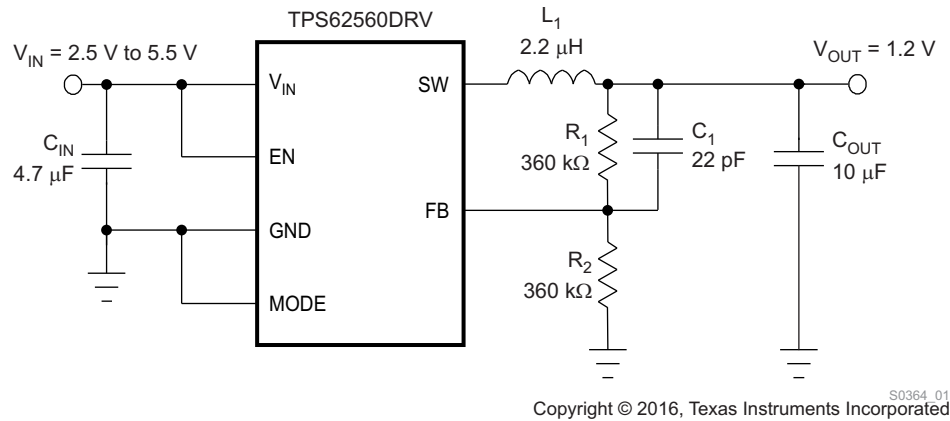


**Figure 28. Typical Operation - PFM Mode**

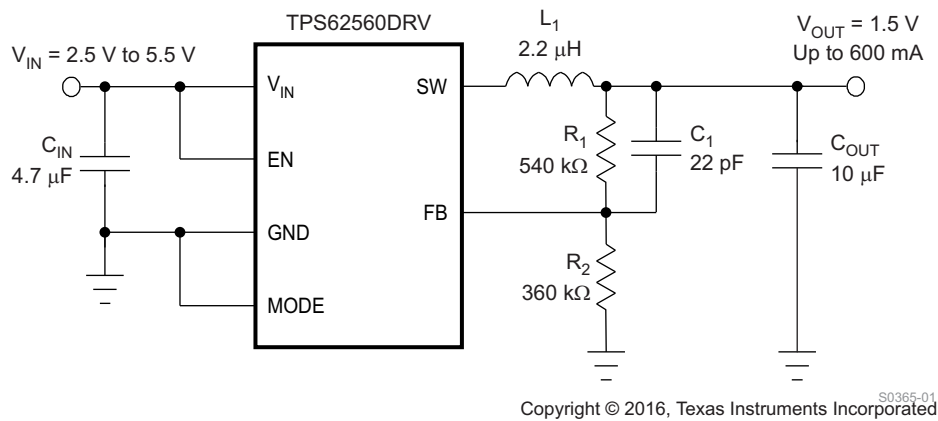


**Figure 29. Typical Operation - PFM Mode**

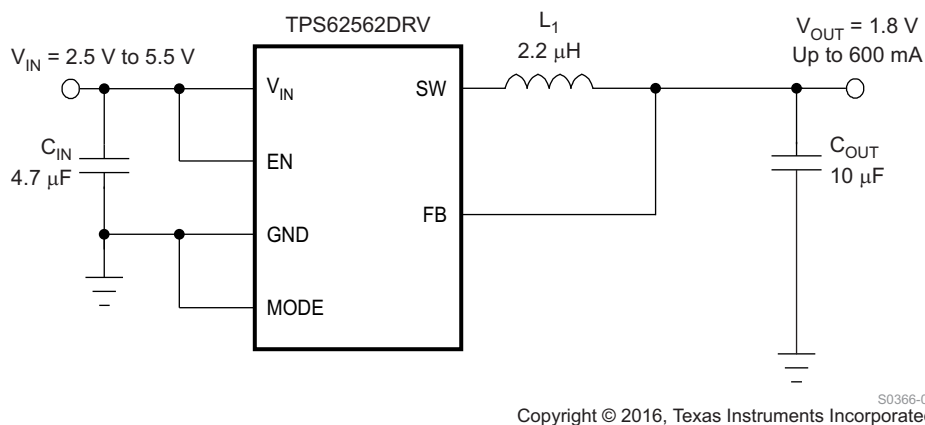
## 9.3 System Examples



**Figure 30. TPS62560 Adjustable 1.2-V Output**



**Figure 31. TPS62560 Adjustable 1.5-V Output**



**Figure 32. TPS62562 Fixed 1.8-V Output**

## 10 Power Supply Recommendations

The TPS6226x device has no special requirements for its input power supply. The input power supply output current must be rated according to the supply voltage, output voltage, and output current of the TPS6226x.

## 11 Layout

### 11.1 Layout Guidelines

As for all switching power supplies, the layout is an important step in the design. Proper function of the device demands careful attention to PCB layout. Take care in board layout to get the specified performance. If the layout is not carefully done, the regulator could show poor line and/or load regulation, stability issues as well as EMI problems. It is critical to provide a low inductance, impedance ground path. Therefore, use wide and short traces for the main current paths. The input capacitor should be placed as close as possible to the IC pins as well as the inductor and output capacitor.

Connect the GND pin of the device to the exposed thermal pad of the PCB and use this pad as a star point. Use a common power GND node and a different node for the signal GND to minimize the effects of ground noise. Connect these ground nodes together to the exposed thermal pad (star point) underneath the IC. Keep the common path to the GND pin, which returns the small signal components and the high current of the output capacitors as short as possible to avoid ground noise. The FB line should be connected right to the output capacitor and routed away from noisy components and traces (for example, the SW line).

### 11.2 Layout Examples

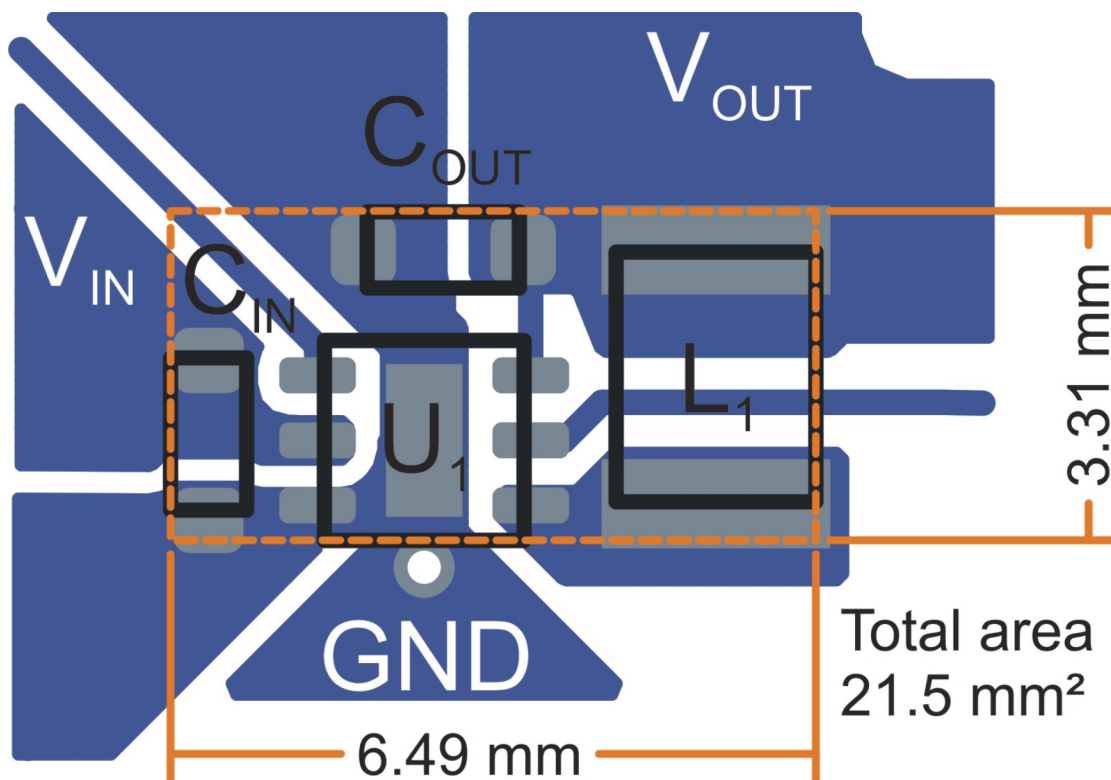


Figure 33. Suggested Layout for Fixed-Output-Voltage Options

## Layout Examples (continued)

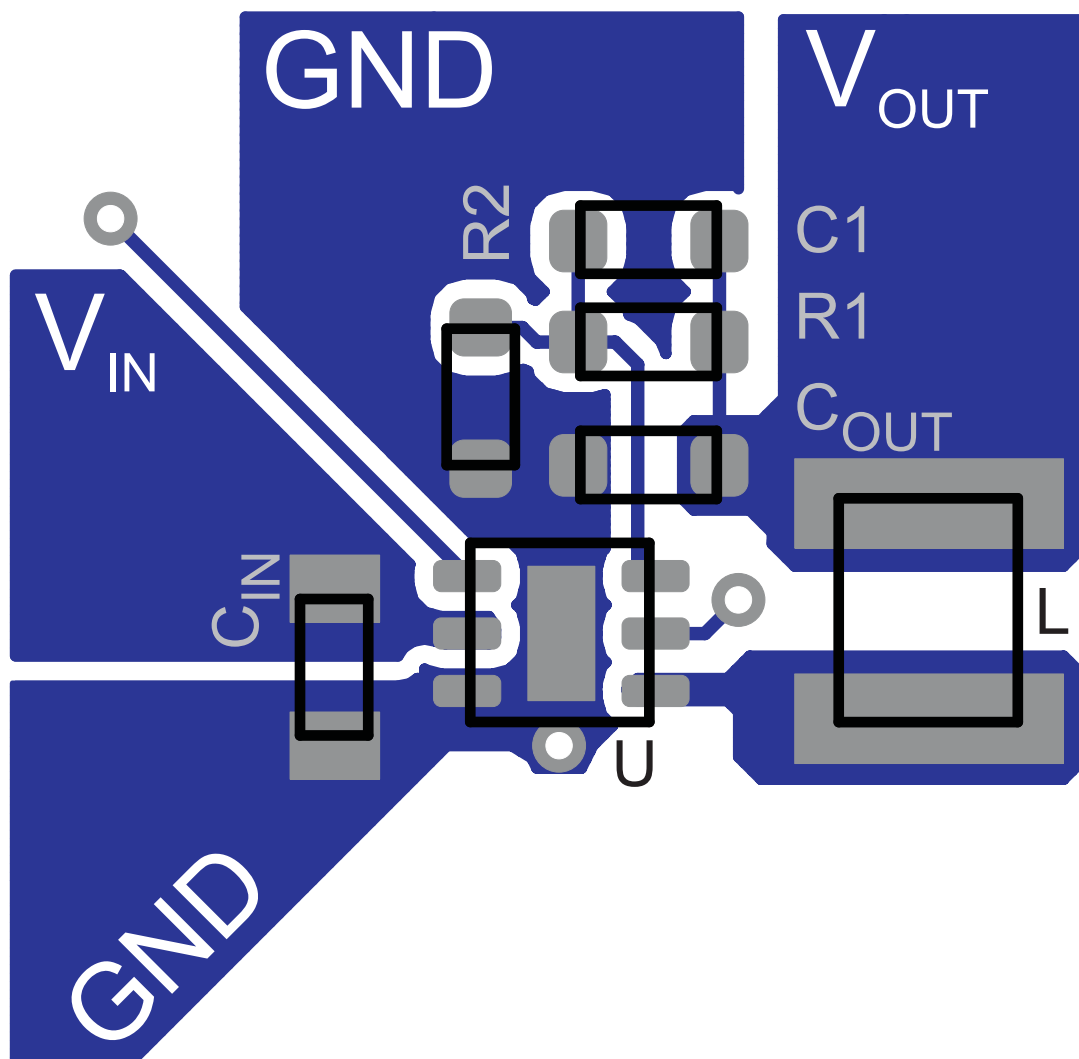


Figure 34. Suggested Layout for Adjustable-Output-Voltage Version

## 12 デバイスおよびドキュメントのサポート

### 12.1 デバイス・サポート

#### 12.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

### 12.2 関連リンク

次の表に、クイック・アクセス・リンクを示します。カテゴリには、技術資料、サポートおよびコミュニティ・リソース、ツールとソフトウェア、およびサンプル注文またはご購入へのクイック・アクセスが含まれます。

**表 3. 関連リンク**

| 製品       | プロダクト・フォルダ              | サンプルとご購入                | 技術資料                    | ツールとソフトウェア              | サポートとコミュニティ             |
|----------|-------------------------|-------------------------|-------------------------|-------------------------|-------------------------|
| TPS62560 | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> |
| TPS62561 | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> |
| TPS62562 | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> | <a href="#">ここをクリック</a> |

### 12.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](#)のデバイス製品フォルダを開いてください。右上の隅にある「通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

### 12.4 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](#), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.5 商標

E2E is a trademark of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 12.6 静電気放電に関する注意事項



これらのデバイスは、限定的なESD(静電破壊)保護機能を内蔵しています。保存時または取り扱い時は、MOSゲートに対する静電破壊を防止するために、リード線同士をショートさせておくか、デバイスを導電フォームに入れる必要があります。

### 12.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

## PACKAGING INFORMATION

| Orderable part number         | Status<br>(1) | Material type<br>(2) | Package   Pins            | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-------------------------------|---------------|----------------------|---------------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPS62560DRV R</a> | Active        | Production           | WSON (DRV)   6            | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CEY                 |
| TPS62560DRV R.A               | Active        | Production           | WSON (DRV)   6            | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CEY                 |
| TPS62560DRV R.B               | Active        | Production           | WSON (DRV)   6            | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CEY                 |
| TPS62560DRV R G4              | Active        | Production           | WSON (DRV)   6            | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CEY                 |
| TPS62560DRV R G4.A            | Active        | Production           | WSON (DRV)   6            | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CEY                 |
| TPS62560DRV R G4.B            | Active        | Production           | WSON (DRV)   6            | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CEY                 |
| <a href="#">TPS62560DRV T</a> | Active        | Production           | WSON (DRV)   6            | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CEY                 |
| TPS62560DRV T.B               | Active        | Production           | WSON (DRV)   6            | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CEY                 |
| <a href="#">TPS62561DDC R</a> | Active        | Production           | SOT-23-<br>THIN (DDC)   5 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CVO                 |
| TPS62561DDC R.A               | Active        | Production           | SOT-23-<br>THIN (DDC)   5 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CVO                 |
| TPS62561DDC R.B               | Active        | Production           | SOT-23-<br>THIN (DDC)   5 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CVO                 |
| TPS62561DDC R G4              | Active        | Production           | SOT-23-<br>THIN (DDC)   5 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CVO                 |
| TPS62561DDC R G4.A            | Active        | Production           | SOT-23-<br>THIN (DDC)   5 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CVO                 |
| TPS62561DDC R G4.B            | Active        | Production           | SOT-23-<br>THIN (DDC)   5 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CVO                 |
| <a href="#">TPS62561DDC T</a> | Active        | Production           | SOT-23-<br>THIN (DDC)   5 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CVO                 |
| TPS62561DDC T.A               | Active        | Production           | SOT-23-<br>THIN (DDC)   5 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CVO                 |
| TPS62561DDC T.B               | Active        | Production           | SOT-23-<br>THIN (DDC)   5 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CVO                 |
| <a href="#">TPS62562DRV R</a> | Active        | Production           | WSON (DRV)   6            | 3000   LARGE T&R      | Yes         | NIPDAU   SN                          | Level-1-260C-UNLIM                | -40 to 85    | NXT                 |
| TPS62562DRV R.A               | Active        | Production           | WSON (DRV)   6            | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | NXT                 |
| TPS62562DRV R.B               | Active        | Production           | WSON (DRV)   6            | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | NXT                 |
| <a href="#">TPS62562DRV T</a> | Active        | Production           | WSON (DRV)   6            | 250   SMALL T&R       | Yes         | NIPDAU   SN                          | Level-1-260C-UNLIM                | -40 to 85    | NXT                 |
| TPS62562DRV T.A               | Active        | Production           | WSON (DRV)   6            | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | NXT                 |

| Orderable part number | Status<br>(1) | Material type<br>(2) | Package   Pins | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-----------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| TPS62562DRVT.B        | Active        | Production           | WSON (DRV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | NXT                 |

- <sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).
- <sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- <sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.
- <sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- <sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- <sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS62560DRVR   | WSO          | DRV             | 6    | 3000 | 179.0              | 8.4                | 2.2     | 2.2     | 1.2     | 4.0     | 8.0    | Q2            |
| TPS62560DRVRG4 | WSO          | DRV             | 6    | 3000 | 179.0              | 8.4                | 2.2     | 2.2     | 1.2     | 4.0     | 8.0    | Q2            |
| TPS62560DRV    | WSO          | DRV             | 6    | 250  | 179.0              | 8.4                | 2.2     | 2.2     | 1.2     | 4.0     | 8.0    | Q2            |
| TPS62561DDCR   | SOT-23-THIN  | DDC             | 5    | 3000 | 179.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS62561DDCRG4 | SOT-23-THIN  | DDC             | 5    | 3000 | 179.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS62561DDCT   | SOT-23-THIN  | DDC             | 5    | 250  | 179.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS62562DRVR   | WSO          | DRV             | 6    | 3000 | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS62562DRV    | WSO          | DRV             | 6    | 250  | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS62560DRVR   | WSN          | DRV             | 6    | 3000 | 200.0       | 183.0      | 25.0        |
| TPS62560DRVRG4 | WSN          | DRV             | 6    | 3000 | 200.0       | 183.0      | 25.0        |
| TPS62560DRVT   | WSN          | DRV             | 6    | 250  | 200.0       | 183.0      | 25.0        |
| TPS62561DDCR   | SOT-23-THIN  | DDC             | 5    | 3000 | 200.0       | 183.0      | 25.0        |
| TPS62561DDCRG4 | SOT-23-THIN  | DDC             | 5    | 3000 | 200.0       | 183.0      | 25.0        |
| TPS62561DDCT   | SOT-23-THIN  | DDC             | 5    | 250  | 200.0       | 183.0      | 25.0        |
| TPS62562DRVR   | WSN          | DRV             | 6    | 3000 | 210.0       | 185.0      | 35.0        |
| TPS62562DRVT   | WSN          | DRV             | 6    | 250  | 210.0       | 185.0      | 35.0        |

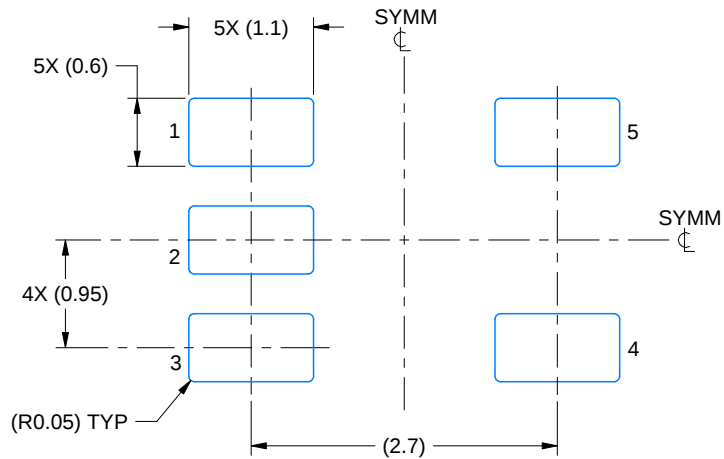


# EXAMPLE BOARD LAYOUT

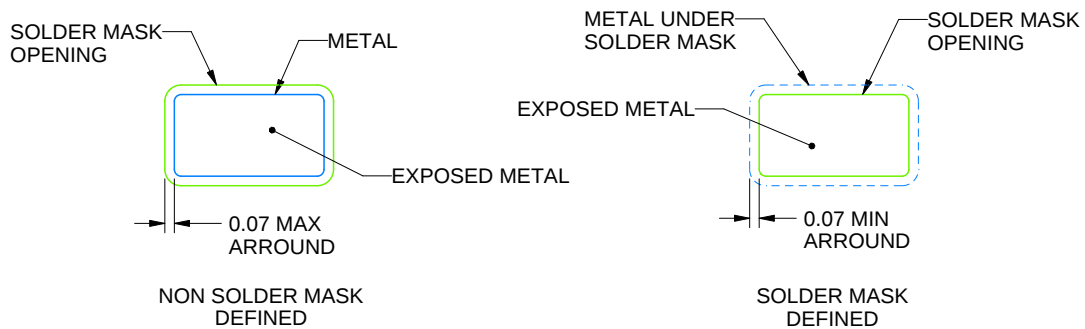
DDC0005A

SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPLODED METAL SHOWN  
SCALE:15X



SOLDERMASK DETAILS

4220752/C 08/2024

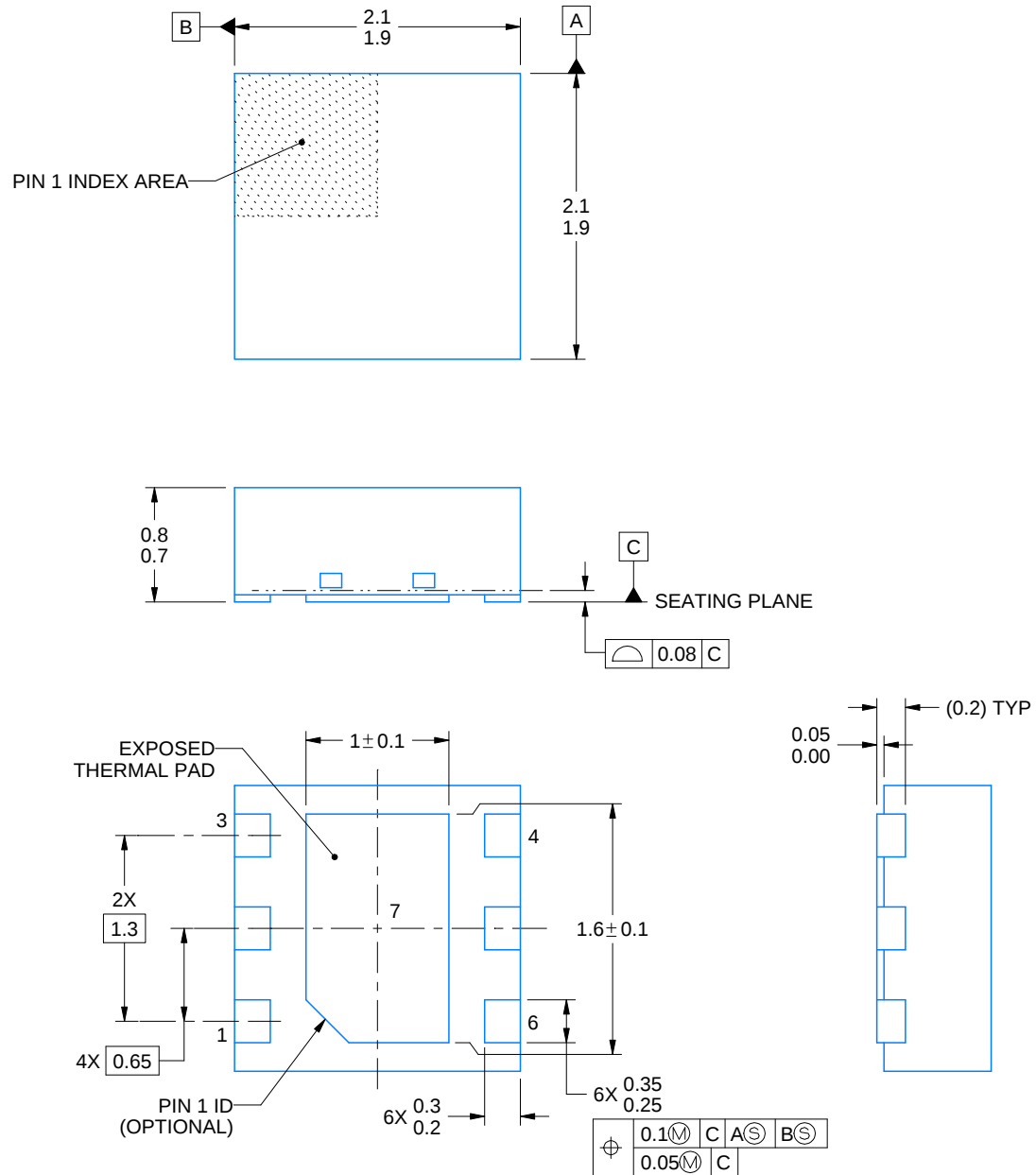
NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4222173/B 04/2018

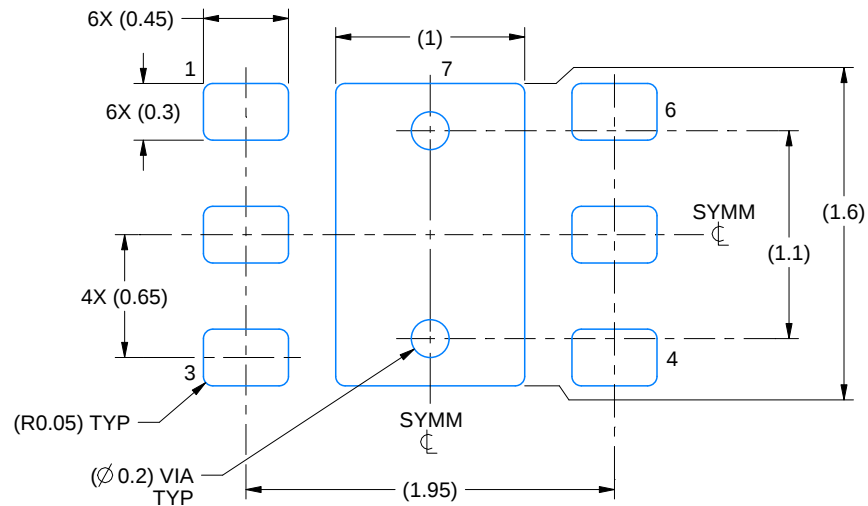
**NOTES:**

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

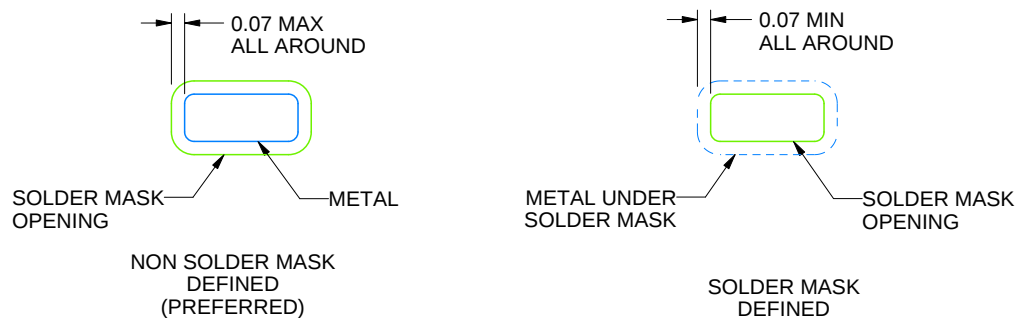
**DRV0006A**

**WSN - 0.8 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
SCALE:25X



## SOLDER MASK DETAILS

4222173/B 04/2018

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

## EXAMPLE STENCIL DESIGN

DRV0006A

WSO - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



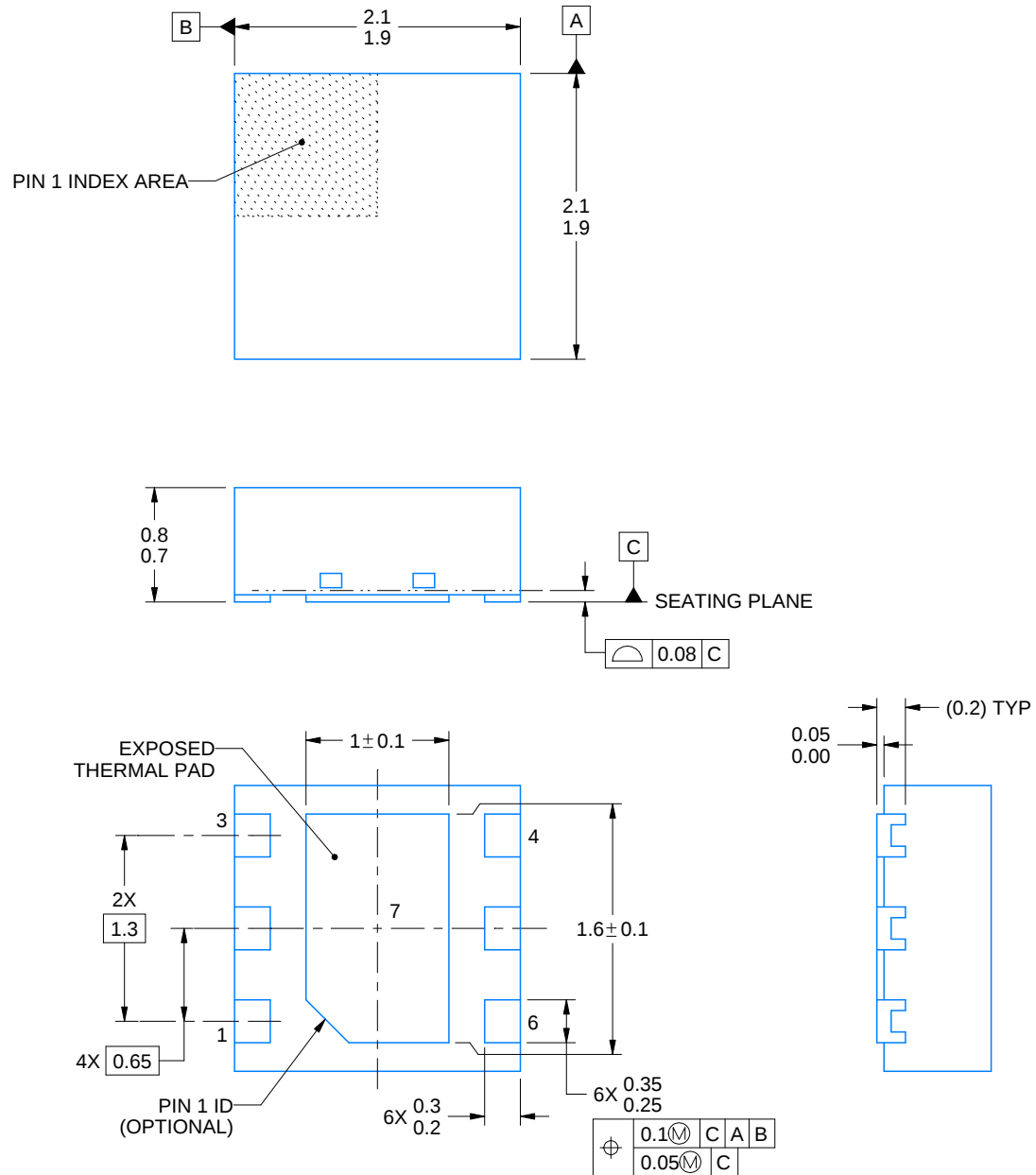
SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7  
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:30X

4222173/B 04/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



4225563/A 12/2019

## NOTES:

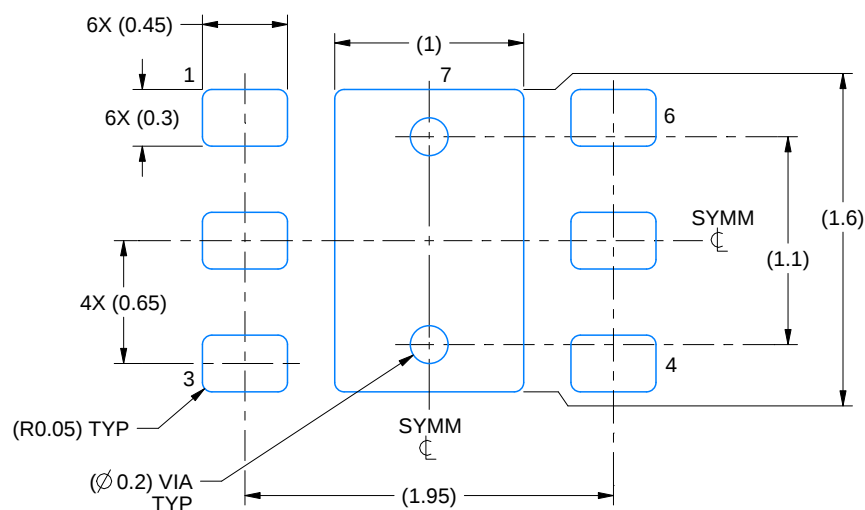
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

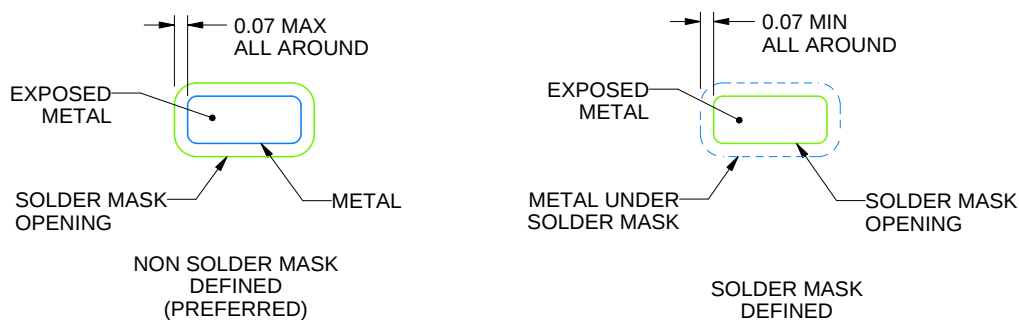
DRV0006D

WSO - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



**LAND PATTERN EXAMPLE**  
EXPOSED METAL SHOWN  
SCALE:25X



**SOLDER MASK DETAILS**

4225563/A 12/2019

NOTES: (continued)

- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
- Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

## EXAMPLE STENCIL DESIGN

DRV0006D

WSO - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7  
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:30X

4225563/A 12/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

## 重要なお知らせと免責事項

テキサス・インスツルメンツは、技術データと信頼性データ (データシートを含みます)、設計リソース (リファレンス デザインを含みます)、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、テキサス・インスツルメンツ製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した テキサス・インスツルメンツ製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとします。

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている テキサス・インスツルメンツ製品を使用するアプリケーションの開発の目的でのみ、テキサス・インスツルメンツはその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。テキサス・インスツルメンツや第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、テキサス・インスツルメンツおよびその代理人を完全に補償するものとし、テキサス・インスツルメンツは一切の責任を拒否します。

テキサス・インスツルメンツの製品は、[テキサス・インスツルメンツの販売条件](#)、または [ti.com](https://www.ti.com) やかかる テキサス・インスツルメンツ製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供されています。テキサス・インスツルメンツがこれらのリソースを提供することは、適用される テキサス・インスツルメンツの保証または他の保証の放棄の拡大や変更を意味するものではありません。

お客様がいかなる追加条項または代替条項を提案した場合でも、テキサス・インスツルメンツはそれらに異議を唱え、拒否します。

郵送先住所：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265  
Copyright © 2025, Texas Instruments Incorporated